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#### TPA0211

SLOS275E - JANUARY 2000 - REVISED NOVEMBER 2016

# **TPA0211 2-W Mono Audio Power Amplifier**

Technical

Documents

## 1 Features

- 2 W Into 4 Ω From 5-V Supply
- 0.6 W Into 4 Ω From 3-V Supply
- Wide Power Supply Compatibility: 3 V to 5 V
- Low Supply Current:
  - 4 mA Typical at 5 V
  - 4 mA Typical at 3 V
- Shutdown Control: 1 µA Typical
- Shutdown Pin Is TTL Compatible
- –40°C to 85°C Operating Temperature Range
- Space-Saving, Thermally-Enhanced MSOP-PowerPAD<sup>™</sup> Packaging

# 2 Applications

- Wireless Communictors
- Notebook PCs
- PDAs
- Other Small Portable Audio Devices

# 3 Description

Tools &

Software

The TPA0211 is a 2-W mono bridge-tied-load (BTL) amplifier designed to drive speakers with as low as 4- $\Omega$  impedance. The device is ideal for small wireless communicators, notebook PCs, PDAs, anyplace a mono speaker and stereo headphones are required. From a 5-V supply, the TPA0211 can deliver 2 W of power into a 4- $\Omega$  speaker.

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The gain of the input stage is set by the user-selected input resistor and a 50-k $\Omega$  internal feedback resistor ( $A_V = -R_F / R_I$ ). The power stage is internally configured with a gain of -1.25 V/V in SE mode, and -2.5 V/V in BTL mode. Thus, the overall gain of the amplifier is -62.5 k $\Omega/R_I$  in SE mode and -125 k $\Omega/R_I$  in BTL mode. The input terminals are high-impedance CMOS inputs, and can be used as summing nodes.

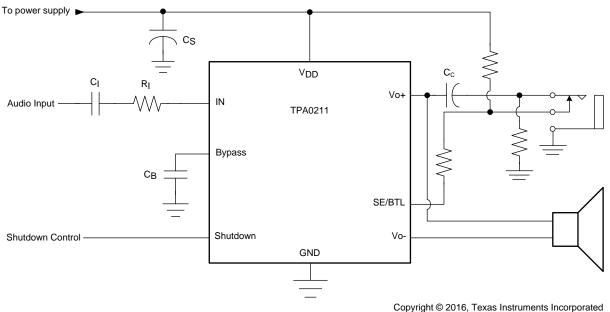
The TPA0211 is available in the 8-pin thermallyenhanced MSOP-PowerPAD package (DGN) and operates over an ambient temperature range of  $-40^{\circ}$ C to 85°C.

#### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)				
TPA0211	MSOP-PowerPAD (8)	3.00 mm × 3.00 mm				

(1) For all available packages, see the orderable addendum at the end of the data sheet.





An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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# 4 Revision History

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NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

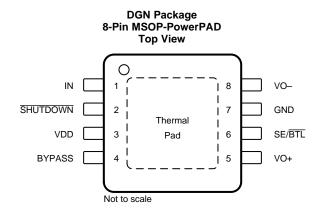
Changes from Revision D	(November 2002) to Revision E	
-------------------------	-------------------------------	--

Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation	
section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and	
Mechanical, Packaging, and Orderable Information section1	1

# 5 Device Comparison Table

DEVICE NUMBER	SPEAKER AMP TYPE	SPECIAL FEATURE	OUTPUT POWER (W)	PSRR (dB)
TPA0211	Class AB	—	2	58
TPA0213	Class AB	—	2	65
TPA0233	Class AB	—	2	58
TPA0253	Class AB	—	1	65

# 6 Pin Configuration and Functions



#### **Pin Functions**

PIN NAME NO.		1/0	DESCRIPTION		
		1/0			
BYPASS	4	I	BYPASS is the tap to the voltage divider for internal mid-supply bias. This terminal must be connected to a $0.1$ - $\mu$ F to $1$ - $\mu$ F capacitor.		
GND	7	_	GND is the ground connection.		
IN	1	I	s the audio input terminal.		
SE/BTL	6	I	en SE/ <u>BTL</u> is held low, the TPA0211 is in BTL mode. en SE/BTL is held high, the TPA0211 is in SE mode.		
SHUTDOWN	2	I	SHUTDOWN places the entire device in shutdown mode when held low. TTL compatible input.		
V <sub>DD</sub>	3	_	V <sub>DD</sub> is the supply voltage terminal.		
V <sub>O+</sub>	5	0	$V_{O+}$ is the positive output for BTL and SE modes.		
V <sub>O-</sub>	8	0	$V_{\text{O}\text{-}}$ is the negative output in BTL mode and a high-impedance output in SE mode.		

# 7 Specifications

### 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

	MIN	МАХ	UNIT
Supply voltage, V <sub>DD</sub>		6	V
Input voltage, V <sub>I</sub>	-0.3	V <sub>DD</sub> + 0.3	V
Continuous total power dissipation		Internally limited (see <i>Dissipation Ratings</i> )	
Lead temperature, 1.6 mm (1/16 inch) from case (10 s)		260	°C
Operating junction temperature, T <sub>J</sub>	-40	150	°C
Storage temperature, T <sub>stg</sub>	-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### 7.2 ESD Ratings

			VALUE	UNIT
V <sub>(ESD)</sub> Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±4000	V	
	Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±1000	v	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

				MIN NO	M MAX	UNIT
$V_{DD}$	Supply voltage			2.5	5.5	V
	V <sub>IH</sub> High-level input voltage	SE/BTL	$V_{DD} = 3 V$	2.7		
$V_{\text{IH}}$		SE/DIL	$V_{DD} = 5 V$	4.5		V
		SHUTDOWN		2		
		SE/BTL	$V_{DD} = 3 V$		1.65	
VIL	/ <sub>IL</sub> Low-level input voltage	SE/DIL	$V_{DD} = 5 V$		2.75	V
		SHUTDOWN			0.8	
T <sub>A</sub>	Operating free-air temperature			-40	85	°C

#### 7.4 Thermal Information

		TPA0211	UNIT           °C/W           °C/W           °C/W           °C/W           °C/W
	THERMAL METRIC <sup>(1)</sup>	DGN (MSOP- PowerPAD)	UNIT
		8 PINS	
$R_{\thetaJA}$	Junction-to-ambient thermal resistance	51.9	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	41.9	°C/W
$R_{\thetaJB}$	Junction-to-board thermal resistance	30.5	°C/W
ΨJT	Junction-to-top characterization parameter	1.5	°C/W
ΨЈВ	Junction-to-board characterization parameter	30.2	°C/W
R <sub>0JC(bot)</sub>	Junction-to-case (bottom) thermal resistance	6	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

# 7.5 Electrical Characteristics – 3 V

 $V_{\text{DD}}$  = 3 V and  $T_{\text{A}}$  = 25°C (unless otherwise noted)

	PARAMETER	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT	
V <sub>OO</sub>	Output offset voltage (measured differentially)	SE/BTL = 0 V, SHUTDOW inputs floating	$\overline{N} = 2 V, R_L = 8 \Omega,$			30	mV	
I <sub>DD(BTL)</sub>	Supply current, BTL mode	SE/BTL = 1.375 V, SHUTE	DOWN = 2 V, V <sub>DD</sub> = 2.5 V		4	6	mA	
I <sub>DD(SE)</sub>	Supply current, SE mode	SE/BTL = 2.25 V, SHUTD	DWN = 2 V, V <sub>DD</sub> = 2.5 V		2	4	mA	
I <sub>DD(SD)</sub>	Supply current, shutdown mode	$SE/\overline{BTL} = 3 V, \overline{SHUTDOW}$	<u>N</u> = 0 V		1	10	μA	
	Lieb level is sut sums at		SHUTDOWN			1		
I <sub>IH</sub>	High-level input current	$V_{DD} = 3.3 \text{ V},  V_{I} = V_{DD}$	SE/BTL			1	μA	
	Low lovel input ourrent	V <sub>DD</sub> = 3.3 V, V <sub>I</sub> = 0 V	SHUTDOWN			1	μA	
I <sub>IL</sub>	Low-level input current	$v_{DD} = 3.3 v, v_1 = 0 v$	SE/BTL			1		
R <sub>F</sub>	Feedback resistor	$\frac{\text{SE}/\overline{\text{BTL}} = 0 \text{ V}, \overline{\text{SHUTDOW}}}{\text{R}_{\text{L}} = 4 \Omega}$	$\overline{N}$ = 2 V, V <sub>DD</sub> = 2.5 V,	45	50	60	kΩ	
OPERAT	ING CHARACTERISTICS, R <sub>L</sub>	= 4 Ω						
Р	Output nouror	THD = 1%, BTL mode, f =	HD = 1%, BTL mode, f = 1 kHz 660					
Po	Output power	THD = 0.1%, SE mode, f =	THD = 0.1%, SE mode, f = 1 kHz, $R_L$ = 32 $\Omega$		33	mW		
THD+N	Total harmonic distortion plus noise	$P_0 = 500 \text{ mW}, \text{ f} = 20 \text{ Hz to}$	9 20 kHz		0.3%			
B <sub>OM</sub>	Maximum output power bandwidth	Gain = 2, THD = 2%			20		kHz	
SNR	Signal-to-noise ratio				88		dB	
M		C <sub>B</sub> = 0.47 μF,	BTL mode, $R_L = 8$ $\Omega, A_V = 8 \text{ dB}$		65		μV <sub>RMS</sub>	
V <sub>n</sub>	Output noise voltage	Output noise voltage $f = 20$ Hz to 20 kHz		$\begin{array}{l} \text{SE mode, } R_{L} = 32 \; \Omega, \\ A_{V} = 2 \; dB \end{array}$		25		

## 7.6 Electrical Characteristics – 5 V

 $V_{DD} = 5 \text{ V}$  and  $T_A = 25^{\circ}\text{C}$  (unless otherwise noted)

PARAMETER		TEST CON	TEST CONDITIONS		TYP	MAX	UNIT	
V <sub>oo</sub>	Output offset voltage (measured differentially)	$SE/\overline{BTL} = 0 V, \overline{SHUTDOWN}$ inputs floating	SE/ $\overline{BTL}$ = 0 V, $\overline{SHUTDOWN}$ = 2 V, R <sub>L</sub> = 8 $\Omega$ , inputs floating			30	mV	
I <sub>DD(BTL)</sub>	Supply current, BTL mode	SE/BTL = 2.75 V, SHUTDO	$\overline{WN} = V_{DD}$		4	6	mA	
I <sub>DD(SE)</sub>	Supply current, SE mode	SE/BTL = 4.5 V, SHUTDOW	$N = V_{DD}$		2	4	mA	
I <sub>DD(SD)</sub>	Supply current, shutdown mode	SE/BTL = 5 V, SHUTDOWN	= 0 V		1	10	μA	
			SHUTDOWN			1		
I <sub>IH</sub>	$ H  \qquad \text{High-level input current} \qquad V_{DD} = 5.5 \text{ V}, \text{ V}_{I} = \text{V}_{D}$		SE/BTL			1	1 µA	
I <sub>IL</sub>   Low-I	Law local Second comments	N 55XXX 6XX	SHUTDOWN			1	μA	
	Low-level input current	V <sub>DD</sub> = 5.5 V, V <sub>I</sub> = 0 V	SE/BTL			1		
OPERAT	ING CHARACTERISTICS, RL	= 4 Ω	· ·					
P <sub>O</sub> Output power		THD = 1%, BTL mode, f = 1	kHz		2		W	
		THD = 0.1%, SE mode, f = 1 kHz, $R_L$ = 32 $\Omega$			92		mW	
THD+N	Total harmonic distortion plus noise	$P_0 = 1.5 \text{ W}, \text{ f} = 20 \text{ Hz to } 20$	P <sub>O</sub> = 1.5 W, f = 20 Hz to 20 kHz		0.2%			
B <sub>OM</sub>	Maximum output power bandwidth	Gain = 2.5, THD = 2%			20		kHz	
SNR	Signal-to-noise ratio				93		dB	
	Output noise voltage	C <sub>B</sub> = 0.47 μF,	$\begin{array}{l} BTL \text{ mode, } R_L = 8 \ \Omega, \\ A_V = 8 \ dB \end{array}$		65		.,	
Vn		f = 20 Hz to 20 kHz	$\begin{array}{l} \text{SE mode, } R_{L} = 32 \; \Omega, \\ A_{V} = 2 \; dB \end{array}$		25		μV <sub>RM</sub>	

#### 7.7 Dissipation Ratings

PACKAGE	T <sub>A</sub> ≤ 25°C	DERATING FACTOR	T <sub>A</sub> = 70°C	T <sub>A</sub> = 85°C
DGN	2.14 W <sup>(1)</sup>	17.1 mW/°C	1.37 W	1.11 W

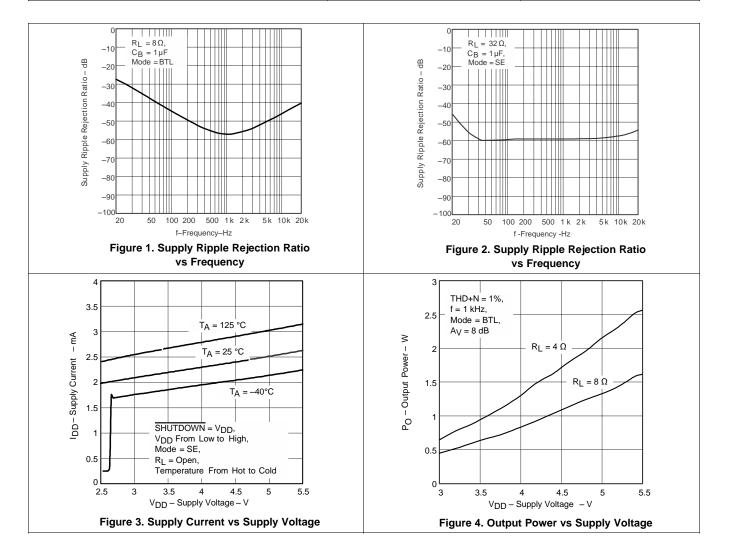
(1) See PowerPAD<sup>™</sup> Thermally Enhanced Package (SLMA002) for more information on the PowerPAD<sup>™</sup> package. The thermal data was measured on a PCB layout based on the information in the section entitled *Texas Instruments Recommended Board for PowerPAD* on page 33 of that document.



# 7.8 Typical Characteristics

## Table 1. Table of Graphs

			FIGURE
	Supply ripple rejection ratio	vs Frequency	Figure 1, Figure 2
I <sub>DD</sub>	Supply current	vs Supply voltage	Figure 3
ſ	Output normal	vs Supply voltage	Figure 4, Figure 5
Po	Output power	vs Load resistance	Figure 6, Figure 7
T I I	Total harmonia diatartian plua paias	vs Frequency	Figure 8, Figure 9, Figure 10, Figure 11
THD+N	Total harmonic distortion plus noise	vs Output power	Figure 12, Figure 13, Figure 14, Figure 15, Figure 16, Figure 17
V <sub>n</sub>	Output noise voltage	vs Frequency	Figure 18, Figure 19
	Closed loop gain and phase		Figure 20, Figure 21

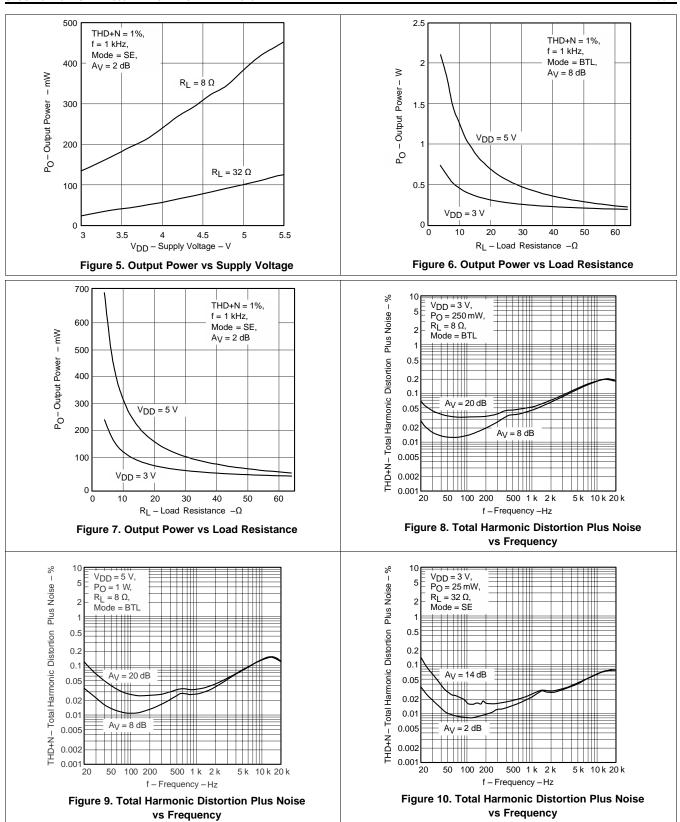




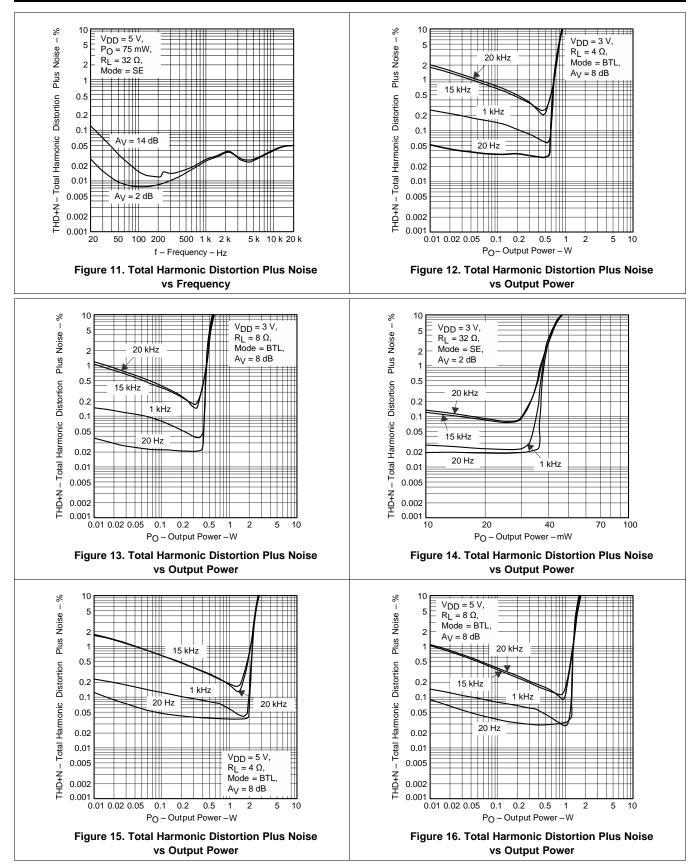
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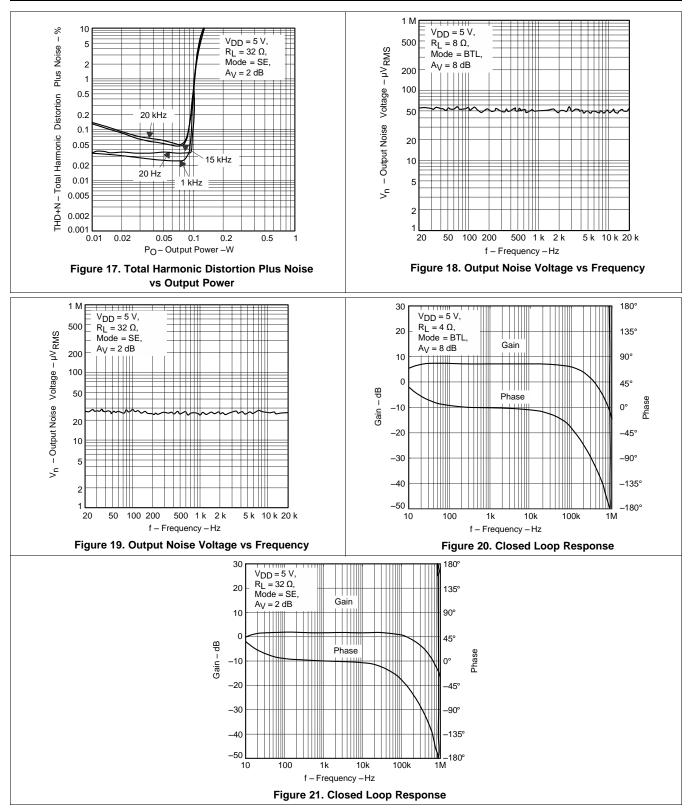




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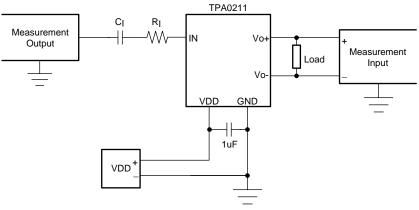




## 8 Parameter Measurement Information

## 8.1 Set-Up for Graphs

All parameters are measured according to the conditions described in *Specifications*. Figure 22 shows the setup used for the typical characteristics of the test device.



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- (1) All other measurements were taken with  $1-\mu F CI$  (unless otherwise noted).
- (2) A 33-µH inductor was placed in series with the load resistor to emulate a small speaker for efficiency measurements.

#### Figure 22. Test Set-Up for Graphs



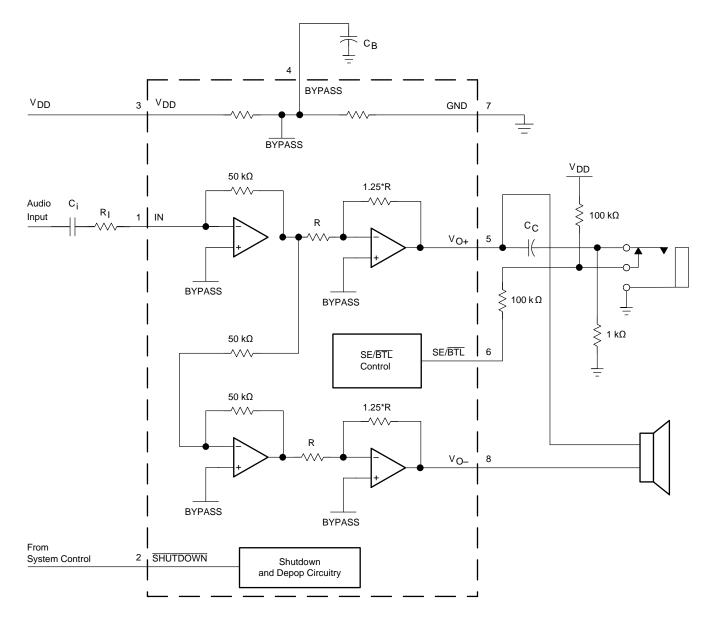
## 9 Detailed Description

#### 9.1 Overview

The TPA0211 device is a Class AB audio power amplifier designed to drive speakers in applications like small wireless communicators, cellphones, notebooks, and so forth. The TPA0211 can deliver 2 W (1% THD+N) of power into a  $4-\Omega$  speaker.

This device is available in the 8-pin thermally-enhanced MSOP-PowerPAD package (DGN) and operates over an ambient temperature range of -40°C to 85°C.

#### 9.2 Functional Block Diagram





#### 9.3 Feature Description

#### 9.3.1 Bridged-Tied Load Versus Single-Ended Mode

Figure 23 shows a Class-AB audio power amplifier (APA) in a BTL configuration. The TPA0211 BTL amplifier consists of two Class-AB amplifiers driving both ends of the load. There are several potential benefits to this differential drive configuration, but initially consider power to the load. The differential drive to the speaker means that as one side is slewing up, the other side is slewing down, and vice versa. This, in effect, doubles the voltage swing on the load as compared to a ground referenced load. Plugging  $2 \times V_{O(PP)}$  into the power equation, where voltage is squared, yields 4 times the output power from the same supply rail and load impedance (see Equation 1 and ).

$$V_{(RMS)} = \frac{V_{O(PP)}}{2\sqrt{2}}$$
  
Power =  $\frac{V_{(RMS)}^{2}}{R_{L}}$ 

. .

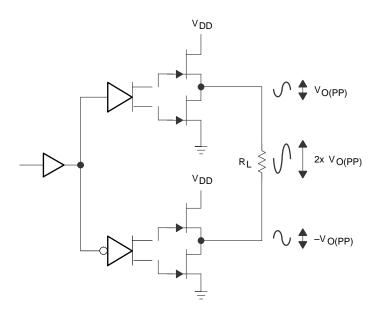


Figure 23. Bridge-Tied Load Configuration

In a typical computer sound channel operating at 5 V, bridging raises the power into an 8- $\Omega$  speaker from a singled-ended (SE, ground reference) limit of 250 mW to 1 W. In sound power, that is a 6-dB improvement — which is loudness that can be heard. In addition to increased power, there are frequency response concerns. Consider the single-supply SE configuration shown in Figure 24. A coupling capacitor is required to block the dc offset voltage from reaching the load. These capacitors can be quite large (approximately 33  $\mu$ F to 1000  $\mu$ F) so they tend to be expensive, heavy, occupy valuable PCB area, and have the additional drawback of limiting low-frequency performance of the system. This frequency limiting effect is due to the high pass filter network created with the speaker impedance and the coupling capacitance and is calculated with Equation 2.

$$f_{\rm c} = \frac{1}{2\pi R_{\rm L} C_{\rm (C)}}$$

For example, a  $68-\mu$ F capacitor with an  $8-\Omega$  speaker would attenuate low frequencies below 293 Hz. The BTL configuration cancels the dc offsets, which eliminates the need for the blocking capacitors. Low-frequency performance is then limited only by the input network and speaker response. Cost and PCB space are also minimized by eliminating the bulky coupling capacitor.

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(1)



#### Feature Description (continued)

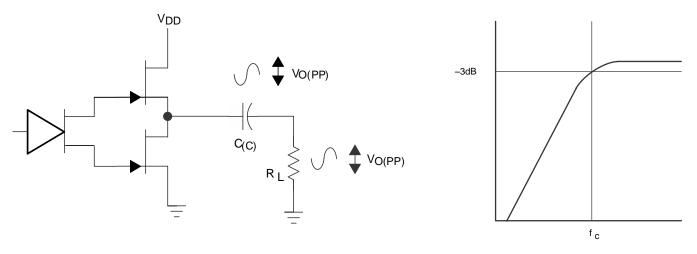


Figure 24. Single-Ended Configuration and Frequency Response

Increasing power to the load does carry a penalty of increased internal power dissipation. The increased dissipation is understandable considering that the BTL configuration produces 4 times the output power of the SE configuration. Internal dissipation versus output power is discussed further in *Crest Factor*.

#### 9.3.2 Single-Ended Operation

In SE mode (see Figure 23 and Figure 24), the load is driven from one amplifier output ( $V_{0+}$ , terminal 5).

The amplifier switches to single-ended operation when the SE/BTL terminal is held high.

#### 9.3.3 BTL Amplifier Efficiency

Class-AB amplifiers are inefficient. The primary cause of inefficiencies is the voltage drop across the output stage transistors. There are two components of the internal voltage drop. One is the headroom or dc voltage drop that varies inversely to output power. The second component is due to the sinewave nature of the output. The total voltage drop can be calculated by subtracting the RMS value of the output voltage from  $V_{DD}$ . The internal voltage drop multiplied by the RMS value of the supply current,  $I_{DD}$ rms, determines the internal power dissipation of the amplifier.

An easy-to-use equation to calculate efficiency starts out as being equal to the ratio of power from the power supply to the power delivered to the load. To accurately calculate the RMS and average values of power in the load and in the amplifier, the current and voltage waveform shapes must first be understood (see Figure 25).

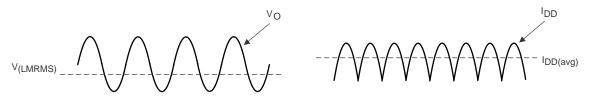


Figure 25. Voltage and Current Waveforms for BTL Amplifiers

Although the voltages and currents for SE and BTL are sinusoidal in the load, currents from the supply are very different between SE and BTL configurations. In an SE application the current waveform is a half-wave rectified shape, whereas in BTL it is a full-wave rectified waveform. This means RMS conversion factors are different. Keep in mind that for most of the waveform both the push and pull transistors are not on at the same time, which supports the fact that each amplifier in the BTL device only draws current from the supply for half the waveform. Equation 3 and Equation 4 are the basis for calculating amplifier efficiency.



#### Feature Description (continued)

Efficiency of a BTL amplifier = 
$$\frac{P_L}{P_{SUP}}$$

where

$$PL = \frac{V_{LRMS}^2}{R_L}$$
, and  $V_{LRMS} = \frac{V_P}{\sqrt{2}}$ , therefore,  $PL = \frac{V_P^2}{2R_L}$ 

and 
$$P_{SUP} = V_{DD}I_{DD}avg$$
 and  $I_{DD}avg = \frac{1}{\pi} \int_{0}^{\pi} \frac{V_{P}}{R_{L}}sin(t) dt = \frac{1}{\pi} \times \frac{V_{P}}{R_{L}}[cos(t)]_{0}^{\pi} = \frac{2V_{P}}{\pi R_{L}}$ 

therefore,

$$\mathsf{P}_{\mathsf{SUP}} = \frac{2\mathsf{V}_{\mathsf{DD}}\mathsf{V}_{\mathsf{P}}}{\pi\mathsf{R}_{\mathsf{L}}}$$

substituting  $P_L$  and  $P_{SUP}$  into equation 9,

Efficiency of a BTL amplifier 
$$=\frac{\frac{V_{P}^{2}}{2R_{L}}}{\frac{2V_{DD}V_{P}}{\pi R_{L}}} = \frac{\pi V_{P}}{4V_{DD}}$$

where

$$V_P = \sqrt{2P_LR_L}$$

therefore,

$$\eta_{\text{BTL}} = \frac{\pi \sqrt{2P_{\text{L}}R_{\text{L}}}}{4V_{\text{DD}}}$$

P <sub>L</sub> = Power delivered to load	V <sub>P</sub> = Peak voltage on BTL load	
P <sub>SUP</sub> =Power drawn from power sup	pply I <sub>DD</sub> avg = Average current drawn from the power supply	
V <sub>LRMS</sub> =RMS voltage on BTL load	V <sub>DD</sub> = Power supply voltage	
$R_L = Load resistance$	$\eta_{BTL} = Efficiency of a BTL amplifier$	(4)

Table 2 employs Equation 3 to calculate efficiencies for four different output power levels. Note that the efficiency of the amplifier is quite low for lower power levels and rises sharply as power to the load is increased resulting in a nearly flat internal power dissipation over the normal operating range. Note that the internal dissipation at full output power is less than in the half power range. Calculating the efficiency for a specific system is the key to proper power supply design.

Table 2. Efficiency	v vs Output Power i	in 5-V 8- $\Omega$ BTL	Systems
---------------------	---------------------	------------------------	---------

OUTPUT POWER (W)	EFFICIENCY (%)	PEAK VOLTAGE (V)	INTERNAL DISSIPATION (W)
0.25	31.4	2	0.55
0.5	44.4	2.83	0.62
1	62.8	4	0.59
1.25	70.2	4.47 <sup>(1)</sup>	0.53

(1) High peak voltages cause the THD to increase.

(3)

A final point to remember about Class-AB amplifiers (either SE or BTL) is how to manipulate the terms in the efficiency equation to utmost advantage when possible. Note that in Equation 3,  $V_{DD}$  is in the denominator. This indicates that as  $V_{DD}$  goes down, efficiency goes up.

#### 9.3.4 Gain Setting Via Input Resistance

The gain of the input stage is set by the user-selected input resistor and a 50-k $\Omega$  internal feedback resistor.

However, the power stage is internally configured with a gain of –1.25 V/V in SE mode, and –2.5 V/V in BTL mode. Thus, the feedback resistor ( $R_F$ ) is effectively 62.5 k $\Omega$  in SE mode and 125 k $\Omega$  in BTL mode. Therefore, the overall gain can be calculated using Equation 5 and Equation 6.

$$A_{V} = \frac{-125 k\Omega}{R_{I}} \quad (BTL)$$

$$A_{V} = \frac{-62.5 k\Omega}{R_{I}} \quad (SE) \quad (SE)$$
(5)

The –3 dB frequency can be calculated using Equation 7.

$$f_{-3db} = \frac{1}{2\pi R_I C_i}$$
(7)

If the filter must be more accurate, the value of the capacitor should be increased while the value of the resistor to ground should be decreased. In addition, the order of the filter could be increased.

#### 9.3.5 Crest Factor

Class-AB power amplifiers dissipate a significant amount of heat in the package under normal operating conditions. A typical music CD requires 12 dB to 15 dB of dynamic range, or headroom above the average power output, to pass the loudest portions of the signal without distortion. In other words, music typically has a crest factor between 12 dB and 15 dB. When determining the optimal ambient operating temperature, the internal dissipated power at the average output power level must be used. The TPA0211 data sheet shows that when the TPA0211 is operating from a 5-V supply into a 4- $\Omega$  speaker 4-W peaks are available. Converting watts to dB with Equation 8.

$$P_{db} = 10 \text{Log} \frac{P_{W}}{P_{ref}} = 10 \text{Log} \frac{4 \text{ W}}{1 \text{ W}} = 6 \text{ dB}$$

Subtracting the headroom restriction to obtain the average listening level without distortion yields :

6 dB - 15 db = -9 dB(15 - dB crest factor) 6 dB - 12 db = -6 dB(12 - dB crest factor) 6 dB - 9 db = -3 dB (9 - dB crest factor) 6 dB - 6 db = 0 dB (6 - dB crest factor)6 dB - 3 db = 3 dB (3 - dB crest factor)

Converting dB back into watts with Equation 9.

$$P_{W} = 10^{PdB/10} \times P_{rof}$$

= 63 mW (18 - dB crest factor)

- = 125 mW (15 dB crest factor)
- = 250 mW (9 dB crest factor)
- = 500 mW (6 dB crest factor)
- = 1000 mW (3 dB crest factor)
- = 2000 mW (15 dB crest factor)

(9)





This is valuable information to consider when attempting to estimate the heat dissipation requirements for the amplifier system. Comparing the absolute worst case, which is 2 W of continuous power output with a 3 dB crest factor, against 12 dB and 15 dB applications drastically affects maximum ambient temperature ratings for the system. Table 3 shows maximum ambient temperatures and TPA0211 internal power dissipation for various output-power levels.

PEAK OUTPUT POWER (W)	AVERAGE OUTPUT POWER	POWER DISSIPATION (W)	MAXIMUM AMBIENT TEMPERATURE
4	2 W (3-dB crest factor)	1.7	–3°C
4	1000 mW (6-dB crest factor)	1.6	6°C
4	500 mW (9-dB crest factor)	1.4	24°C
4	250 mW (12-dB crest factor)	1.1	51°C
4	125 mW (15-dB crest factor)	0.8	78°C
4	63 mW (18-dB crest factor)	0.6	96°C

As a result, Equation 10 for calculating  $P_{Dmax}$  may be used for an 4- $\Omega$  application.

$$\mathsf{P}_{\mathsf{Dmax}} = \frac{2\mathsf{V}^2_{\mathsf{DD}}}{\pi^2\mathsf{R}_{\mathsf{L}}} \tag{10}$$

However, in the case of a 4- $\Omega$  load, the P<sub>Dmax</sub> occurs at a point well above the normal operating power level. The amplifier may therefore be operated at a higher ambient temperature than required by the P<sub>Dmax</sub> formula for a 4- $\Omega$  load.

### 9.4 Device Functional Modes

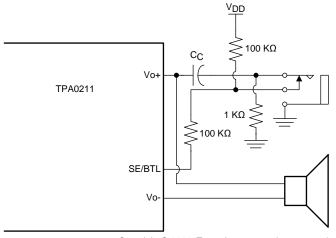
#### 9.4.1 Shutdown Mode

The TPA0211 amplifier can be put in shutdown mode when asserting shutdown pin to a logic LOW. While in shutdown mode, the device output stage is turned off and the current consumption is very low.

#### 9.4.2 SE/BTL (Stereo/Mono) Operation

The ability of the TPA0211 to easily switch between mono BTL and stereo SE modes is one of its most important cost saving features. This feature eliminates the requirement for an additional headphone amplifier in applications where an internal speaker is driven in BTL mode but an external headphone must be accommodated. When SE/BTL is held high for <u>SE</u> mode, the V<sub>O</sub> output goes into a high impedance state while the V<sub>O+</sub> output operates normally. When SE/BTL is held low, the V<sub>O</sub> output operates normally, placing the amplifier in BTL mode.

#### **Device Functional Modes (continued)**



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Figure 26. TPA0211 Resistor Divider Network Circuit

Using a readily available 1/8-in (3.5 mm) mono headphone jack, the control switch is closed when no plug is inserted. When closed, the 100-k $\Omega$ , 1-k $\Omega$  divider pulls the SE/BTL input low. When a plug is inserted, the 1-k $\Omega$  resistor is disconnected and the SE/BTL input is pulled high.



## **10** Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

#### **10.1** Application Information

These typical connection diagrams highlight the required external components and system level connections for proper operation of the device. Each of these configurations can be realized using the Evaluation Modules (EVMs) for the device. These flexible modules allow full evaluation of the device in the most common modes of operation. Any design variation can be supported by TI through schematic and layout reviews. Visit e2e.ti.com for design assistance and join the audio amplifier discussion forum for additional information.

### **10.2 Typical Application**

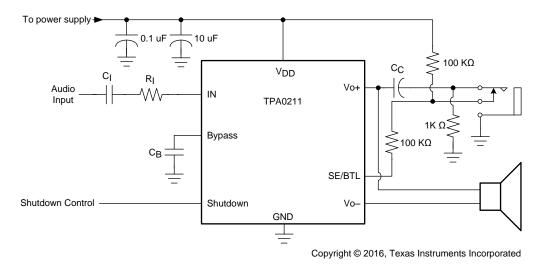


Figure 27. TPA0211 With SE/BTL Operation

#### 10.2.1 Design Requirements

For this example, Table 4 lists the design parameters.

Table 4. Design Farameters		
PARAMETER	VALUE	
Power supply	5 V	
Enable inputs	High > 2 V	
	Low < 0.8 V	
Speaker	8 Ω	

Table 4. Design I	Parameters
-------------------	------------

#### 10.2.2 Detailed Design Procedure

#### 10.2.2.1 Surface Mount Capacitor

Low-ESR capacitors are recommended throughout this applications section. A real (as opposed to ideal) capacitor can be modeled simply as a resistor in series with an ideal capacitor. The voltage drop across this resistor minimizes the beneficial effects of the capacitor in the circuit. The lower the equivalent value of this resistance the more the real capacitor behaves like an ideal capacitor.

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Temperature and applied DC voltage influence the actual capacitance of high-K materials. Table 5 shows the relationship between the different types of high-K materials and their associated tolerances, temperature coefficients, and temperature ranges. Notice that a capacitor made with X5R material can lose up to 15% of its capacitance within its working temperature range.

In an application, the working capacitance of components made with high-K materials is generally much lower than nominal capacitance. A worst case result with a typical X5R material might be -10% tolerance, -15% temperature effect, and -45% DC voltage effect at 50% of the rated voltage. This particular case would result in a working capacitance of 42% (0.9 × 0.85 × 0.55) of the nominal value.

Select high-K ceramic capacitors according to the following rules:

- 1. Use capacitors made of materials with temperature coefficients of X5R, X7R, or better.
- 2. Use capacitors with DC voltage ratings of at least twice the application voltage. Use minimum 10-V capacitors for this device.
- 3. Choose a capacitance value at least twice the nominal value calculated for the application. Multiply the nominal value by a factor of 2 for safety. If a 10-µF capacitor is required, use 20 µF.

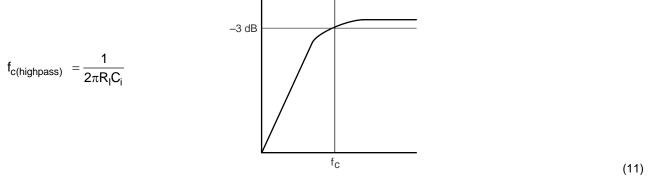
The preceding rules and recommendations apply to capacitors used in connection with the device. This device cannot meet its performance specifications if the rules and recommendations are not followed.

MATERIAL	TYPICAL TOLERANCE	TEMPERATURE	TEMPERATURE RANGE (°C)
COG/NOP	±5%	±30 ppm	-55 to 125
X7R	±10%	±15%	-55 to 125
X5R	80% to -20%	22% to -82%	-30 to 85

Table 5. Typical Tolerance and Temperature Coefficient of Capacitance by Material

#### 10.2.2.2 Input Capacitor, C<sub>i</sub>

In the typical application an input capacitor,  $C_i$ , is required to allow the amplifier to bias the input signal to the proper dc level for optimum operation. In this case,  $C_i$  and the input resistance of the amplifier,  $R_i$ , form a high-pass filter with the corner frequency determined in Equation 11.



The value of  $C_i$  is important to consider as it directly affects the bass (low frequency) performance of the circuit. Consider the example where  $R_i$  is 10 k $\Omega$  and the specification calls for a flat bass response down to 40 Hz. Equation 6 is reconfigured as Equation 12.

$$C_{i} = \frac{1}{2\pi R_{i} f_{c}}$$
(12)

In this example,  $C_I$  is 0.4  $\mu$ F so one would likely choose a value in the range of 0.47  $\mu$ F to 1  $\mu$ F. A further consideration for this capacitor is the leakage path from the input source through the input network ( $C_i$ ) and the feedback network to the load. This leakage current creates a dc offset voltage at the input to the amplifier that reduces useful headroom, especially in high gain applications. For this reason a low-leakage tantalum or ceramic capacitor is the best choice. When polarized capacitors are used, the positive side of the capacitor should face the amplifier input in most applications as the dc level there is held at  $V_{DD}/2$ , which is likely higher than the source dc level. Note that it is important to confirm the capacitor polarity in the application.



#### 10.2.2.3 Power Supply Decoupling, C<sub>(S)</sub>

The TPA0211 is a high-performance CMOS audio amplifier that requires adequate power supply decoupling to ensure the output total harmonic distortion (THD) is as low as possible. Power supply decoupling also prevents oscillations for long lead lengths between the amplifier and the speaker. The optimum decoupling is achieved by using two capacitors of different types that target different types of noise on the power supply leads. For higher frequency transients, spikes, or digital hash on the line, a good low equivalent-series-resistance (ESR) ceramic capacitor, typically 0.1  $\mu$ F placed as close as possible to the device V<sub>DD</sub> lead, works best. For filtering lower-frequency noise signals, TI recommends a larger aluminum electrolytic capacitor of 10  $\mu$ F or greater placed near the audio power amplifier.

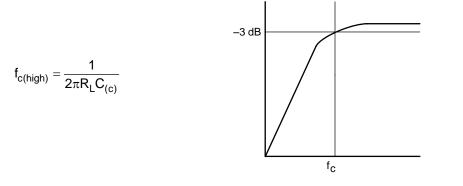
#### 10.2.2.4 Midrail Bypass Capacitor, C<sub>(BYP)</sub>

The midrail bypass capacitor,  $C_{(BYP)}$ , is the most critical capacitor and serves several important functions. During start-up or recovery from shutdown mode,  $C_{(BYP)}$  determines the rate at which the amplifier starts up. The second function is to reduce noise produced by the power supply caused by coupling into the output drive signal. This noise is from the midrail generation circuit internal to the amplifier, which appears as degraded PSRR and THD+N.

Bypass capacitor,  $C_{(BYP)}$ , values of 0.47  $\mu$ F to 1  $\mu$ F ceramic or tantalum low-ESR capacitors are recommended for the best THD and noise performance.

#### 10.2.2.5 Output Coupling Capacitor, C<sub>(C)</sub>

In the typical single-supply SE configuration, an output coupling capacitor ( $C_{(C)}$ ) is required to block the dc bias at the output of the amplifier thus preventing dc currents in the load. As with the input coupling capacitor, the output coupling capacitor and impedance of the load form a high-pass filter governed by Equation 13.



The main disadvantage, from a performance standpoint, is that the load impedances are typically small, which drives the low-frequency corner higher, degrading the bass response. Large values of  $C_{(C)}$  are required to pass low frequencies into the load. Consider the example where a  $C_{(C)}$  of 330 µF is chosen and loads vary from 3  $\Omega$ , 4  $\Omega$ , 8  $\Omega$ , 32  $\Omega$ , 10 k $\Omega$ , to 47 k $\Omega$ . Table 6 summarizes the frequency response characteristics of each configuration.

•		
RL	C <sub>(C)</sub>	LOWEST FREQUENCY
3 Ω	330 µF	161 Hz
4 Ω	330 µF	120 Hz
8 Ω	330 µF	60 Hz
32 Ω	330 µF	15 Hz
10,000 Ω	330 µF	0.05 Hz
47,000 Ω	330 µF	0.01 Hz

# Table 6. Common Load Impedances vs Low Frequency Output Characteristics in SE Mode

(13)

As Table 6 indicates, most of the bass response is attenuated into a 4- $\Omega$  load, an 8- $\Omega$  load is adequate, headphone response is good, and drive into line level inputs (a home stereo for example) is exceptional.

Furthermore, the total amount of ripple current that must flow through the capacitor must be considered when choosing the component. As shown in the application circuit, one coupling capacitor must be in series with the mono loudspeaker for proper operation of the stereo-mono switching circuit. For a 4- $\Omega$  load, this capacitor must be able to handle about 700 mA of ripple current for a continuous output power of 2 W.

#### 10.2.3 Application Curves

Table 7 lists the figures for the application curves.

DESCRIPTION	FIGURE <sup>(1)</sup>
Supply current vs Supply voltage	Figure 3
Output power vs Load resistance	Figure 6
THD+N vs Frequency	Figure 8
THD+N vs Output power	Figure 12

 Table 7. Table of Graphs

(1) All figures are located in *Typical Characteristics*.



## **11** Power Supply Recommendations

The TPA0211 is designed to operate from an input voltage supply range from 2.5 V to 5.5 V. Therefore, the output voltage range of the power supply must be within this range. The current capability of upper power must not exceed the maximum current limit of the power switch.

#### 11.1 Power Supply Decoupling Capacitors

The TPA0211 requires adequate power supply decoupling to ensure a high efficiency operation with low total harmonic distortion (THD). Place a low equivalent-series-resistance (ESR) ceramic capacitor, typically 0.1  $\mu$ F, within 2 mm of the VDD pin. This choice of capacitor and placement helps with higher frequency transients, spikes, or digital hash on the line. In addition to the 0.1- $\mu$ F ceramic capacitor, is recommended to place a 2.2- $\mu$ F to 10- $\mu$ F capacitor on the VDD supply trace. This larger capacitor acts as a charge reservoir, providing energy faster than the board supply, thus helping to prevent any droop in the supply voltage.

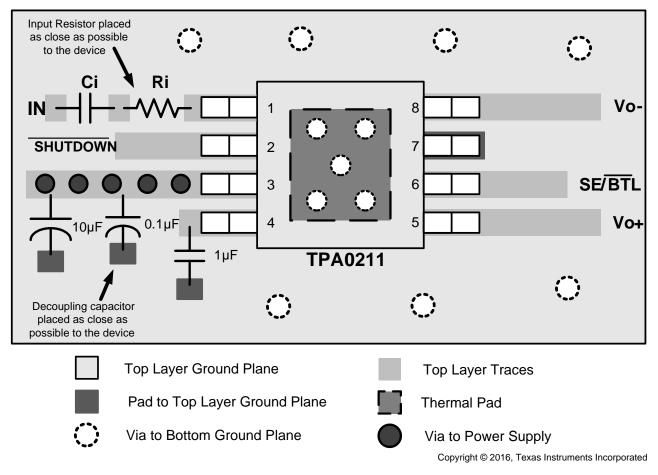
# 12 Layout

#### 12.1 Layout Guidelines

#### 12.1.1 Component Placement

Keeping the external components very close to the TPA0211 to limit noise pickup is very important to limit noise pickup. Placing the decoupling capacitors as close as possible to the device is important for the performance of the class-AB amplifier.

#### 12.2 Layout Example



#### Figure 28. Layout Recommendation



#### **12.3 Thermal Considerations**

The maximum ambient temperature depends on the heat sinking ability of the PCB system. The derating factor for the DGN package is shown in the *Dissipation Ratings*. Converting this  $\theta_{JA}$  can be done with Equation 14.

$$\Theta_{JA} = \frac{1}{\text{Derating Factor}} = \frac{1}{0.0171} = 58.48^{\circ} \text{C} / \text{W}$$
 (14)

To calculate maximum ambient temperatures, first consider that the numbers from the dissipation graphs are per channel so the dissipated power needs to be doubled for two channel operation. Given  $R_{\theta JA}$ , the maximum allowable junction temperature, and the total internal dissipation, the maximum ambient temperature can be calculated with Equation 15. The maximum recommended junction temperature for the TPA0211 is 150°C.

 $T_AMax = T_IMax - \Theta_{IA}P_D = 150 - 58.48(0.8 \times 2) = 56^{\circ}C(15 - dB \text{ crest factor})$ 

(15)

#### NOTE

Internal dissipation of 0.8 W is estimated for a 2-W system with 15-dB crest factor per channel.

Table 3 shows that for some applications no airflow is required to keep junction temperatures in the specified range. The TPA0211 is designed with thermal protection that turns the device off when the junction temperature surpasses 150°C to prevent damage to the IC. Table 3 was calculated for maximum listening volume without distortion. When the output level is reduced the numbers in the table change significantly. Also, using 8- $\Omega$  speakers dramatically increases the thermal performance by increasing amplifier efficiency.



# **13 Device and Documentation Support**

### **13.1 Documentation Support**

#### 13.1.1 Related Documentation

For related documentation see the following:

- PowerPAD<sup>™</sup> Thermally Enhanced Package (SLMA002)
- Guidelines for Measuring Audio Power Amplifier Performance (SLOA068)
- TPA0211EVM User Guide (SLOU092)

### 13.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

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#### 13.4 Trademarks

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#### 13.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### 13.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

# 14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



8-Sep-2017

# PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
TPA0211DGN	ACTIVE	MSOP- PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	AEG	Samples
TPA0211DGNG4	ACTIVE	MSOP- PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	AEG	Samples
TPA0211DGNR	ACTIVE	MSOP- PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	AEG	Samples
TPA0211DGNRG4	ACTIVE	MSOP- PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	AEG	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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# PACKAGE MATERIALS INFORMATION

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# TAPE AND REEL INFORMATION





# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nomina	al											
Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPA0211DGNR	MSOP- Power PAD	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPA0211DGNR	MSOP- Power PAD	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

TEXAS INSTRUMENTS

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# PACKAGE MATERIALS INFORMATION

3-Aug-2017



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPA0211DGNR	MSOP-PowerPAD	DGN	8	2500	364.0	364.0	27.0
TPA0211DGNR	MSOP-PowerPAD	DGN	8	2500	358.0	335.0	35.0

DGN (S-PDSO-G8)

PowerPAD<sup>™</sup> PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <a href="http://www.ti.com">http://www.ti.com</a>.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions. F. Falls within JEDEC MO-187 variation AA-T

PowerPAD is a trademark of Texas Instruments.



# DGN (S-PDSO-G8)

# PowerPAD<sup>™</sup> PLASTIC SMALL OUTLINE

#### THERMAL INFORMATION

This PowerPAD  $^{M}$  package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.





4206323-2/1 12/11

NOTE: All linear dimensions are in millimeters

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# DGN (R-PDSO-G8)

# PowerPAD<sup>™</sup> PLASTIC SMALL OUTLINE



NOTES:

- : A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
  - D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>.
  - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
  - F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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